TOSHIBA Fast Recovery Diode Silicon Diffused Type

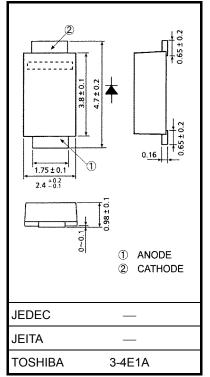
CMF01

Switching Mode Power Supply Applications DC/DC Converter Applications

- Repetitive peak reverse voltage: VRRM = 600 V
- Average forward current: $I_F(AV) = 2.0 A$
- Forward voltage: V_{FM} = 2.0 V (max)
- Very fast reverse-recovery time: $t_{rr} = 100 \text{ ns} \text{ (max.)}$
- Suitable for compact assembly due to small surface-mount package "M-FLATTM" (Toshiba package name)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}	600	V
Average forward current	I _{F (AV)}	2.0 (Note 1)	А
Peak one-cycle surge forward current (non-repetitive)	I _{FSM}	30 (50 Hz)	A
Junction temperature	Tj	-40~150	°C
Storage temperature range	T _{stg}	-40~150	°C



Weight: 0.023 g (typ.)

Note 1: T{ = 100°C

Device mounted on a ceramic board Board size: 50 mm × 50 mm, Soldering land size: 2 mm × 2 mm Board thickness: 0.64 t Rectangular waveform (α = 180°)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

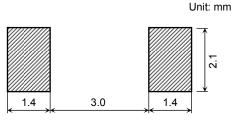
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Peak forward voltage	V _{FM}	I _{FM} = 2.0 A (pulse test)	_	1.4	2.0	V	
Repetitive peak reverse current	I _{RRM}	V _{RRM} = 600 V (pulse test)	_		50	μA	
Reverse recovery time	trr	$I_{\rm F}$ = 1 A, di/dt =-30 A/ μ s	_		100	ns	
Forward recovery time	tfr	I _F = 1 A	_	270	_	ns	
Thermal resistance	R _{th (j-a)}	Device mounted on a ceramic board (board size: 50 mm × 50 mm) (soldering land: 2 mm × 2 mm) (board thickness: 0.64 t)	_		60	30	
		Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) — (soldering land: 6 mm × 6 mm) (board thickness: 1.6 t)		_	135	°C/W	
		Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) (soldering land: 2.1 mm × 1.4 mm) (board thickness: 1.6 t)		_	210		
Thermal resistance (junction to lead)	R _{th (j-ℓ)}	—			16	°C/W	

Marking

Abbreviation Code	Part No.
F1	CMF01

Standard Soldering Pad



Handling Precautions

The absolute maximum ratings denote the absolute maximum ratings, which are rated values and must not be exceeded during operation, even for an instant. The following are the general derating methods we recommend for designing a circuit using this device.

- V_{RRM}: We recommend that the worst-case voltage, including surge voltage, be no greater than 80% of the absolute maximum rating of V_{RRM} for a DC circuit; and no greater than 50% of that of V_{RRM} for an AC circuit. V_{RRM} has a temperature coefficient (0.1%/°C). Be sure to take this temperature coefficient into account when
 - designing a device for use at low temperature.
- I_F(AV): We recommend that the worst case current be no greater than 80% of the absolute maximum rating of I_F(AV). Carry out sufficient heat design. If it is not possible to design a circuit with excellent heat radiation, set a margin by using an allowable Tamax-IF (AV) curve.

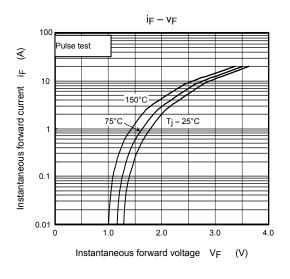
This rating specifies the non-repetitive peak current in one cycle of a 50 Hz sine wave, condition angle 180°. Therefore the rating applies only to abnormal operation, which seldom occurs during the lifespan of a device.

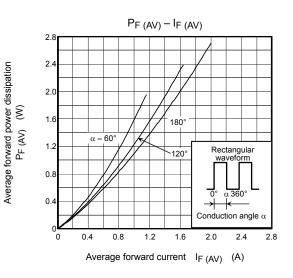
For this device, we recommend a Tj of below 120 $^\circ\!\mathrm{C}$ under the worst load and heat radiation conditions.

Thermal resistance between junction and ambient fluctuates depending on the mounting condition of the device. When using the device, be sure to design the circuit board and soldering land size to match the appropriate thermal resistance value.

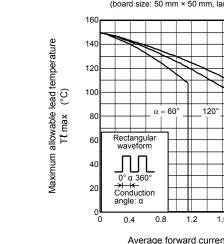
Refer to the Rectifier databook for further information.

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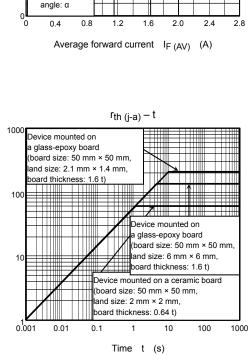


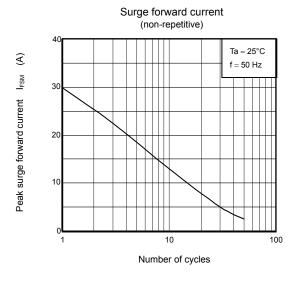
Ta max – IF (AV) Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm, land size: 6 mm × 6 mm) 160 Maximum allowable ambient temperature 140 120 Ta max (°C) 100 80 Rectangular waveform 60 120 $\alpha = 60^{\circ}$ ШL 40 0° α 360° → K Conduction 20 180 angle: a 0L 0 0.4 0.8 12 1.6 24 20 2.8 Average forward current IF (AV) (A)



T{ max - I_F (AV) Device mounted on a ceramic board (board size: 50 mm × 50 mm, land size: 2 mm × 2 mm)

180°





2006-11-07

Transient thermal impedance

rth (j-a) (°C/W)

RESTRICTIONS ON PRODUCT USE

20070701-EN

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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